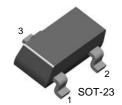


February 2008

MMBT5770 NPN RF Transistor

- This device is designed for use as RF amplifiers, oscillators and multipliers with collector currents in the 1.0 mA to 30 mA range.
- Sourced from process 43.



1. Base 2. Emitter 3. Collector

Absolute Maximum Ratings $T_a = 25$ °C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{CBO}	Collector-Base Voltage	30	V	
V _{CEO}	Collector-Emitter Voltage	15	V	
V _{EBO}	Emitter-Base Voltage	4.5	V	
I _C	Collector Current - Continuous	10	mA	
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 to +150	°C	

Thermal Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
P_{D}	Total Device Dissipation Derate above 25°C	225 1.8	mW mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	556	°C/W

^{*} Device mounted on FR-4PCB 1.6" \times 1.6" \times 0.06".

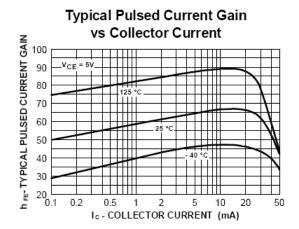
Electrical Characteristics T_a=25°C unless otherwise noted

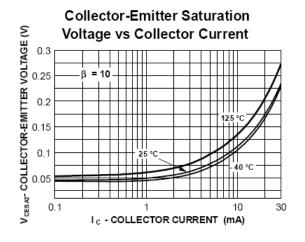
Symbol	Parameter	Test Condition	Min.	Max.	Units		
Off Charact	Off Characteristics						
V _{(BR)CBO}	Collector-Base Breakdown Voltage	Ic = 1.0 μA, Iε = 0	30		V		
V _{CEO(sus)}	Collector-Emitter Sustaining Voltage*	Ic = 3.0 mA, I _B = 0	15		V		
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	IE = 10 μA, Ic = 0	3		V		
I _{CBO}	Collector-Cutoff Current	VcB = 15 V, IE = 0		50	nA		
On Characteristics *							
h _{FE}	DC Current Gain	V _{CE} = 1.0V, I _C = 3.0mA	30				
V _{CE (sat)}	Collector-Emitter Saturation Voltage	I _C = 10mA, I _B = 1.0mA		0.4	V		
V _{BE (sat)}	Base-Emitter Saturation Voltage	I _C = 10mA, I _B = 1.0mA		1.0	V		
Small Signa	Small Signal Characteristics						
f _T	Current Gain Bandwidth Product	I _C = 4.0mA, V _{CE} = 10V, f = 100MHz	600		MHz		

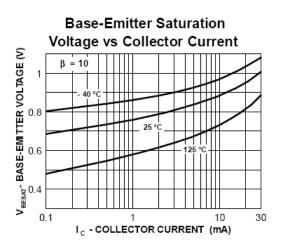
1

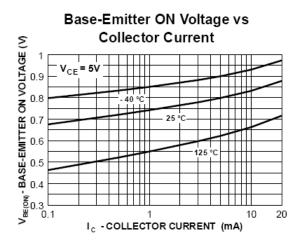
^{*} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%

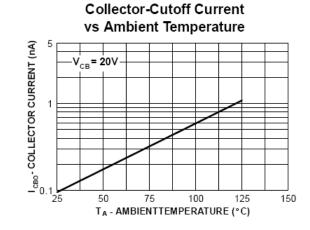
Typical Characteristics

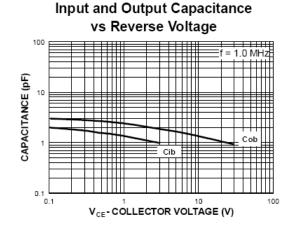




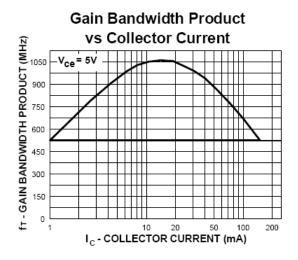




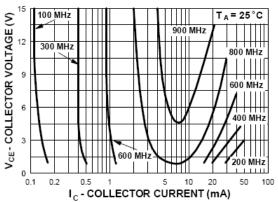




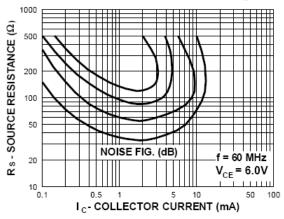
Typical Characteristics (continued)



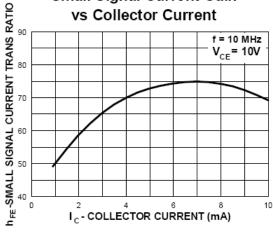
Contours of Constant Gain Bandwidth Product (f_T)



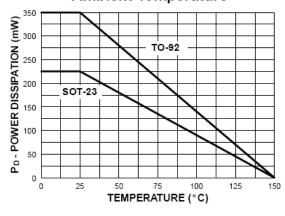
Contours of Constant Noise Figure



Small Signal Current Gain

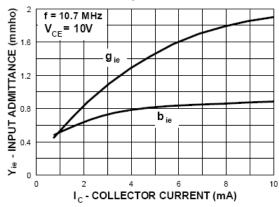


Power Dissipation vs Ambient Temperature

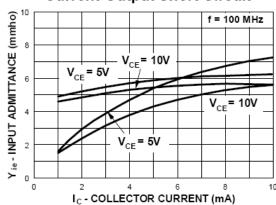


Typical Characteristics (continued)

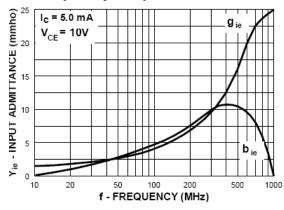
Input Admittance vs Collector **Current-Output Short Circuit**



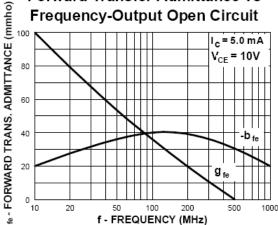
Input Admittance vs Collector **Current-Output Short Circuit**



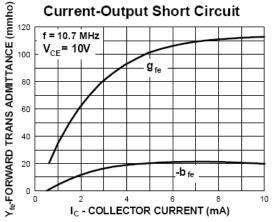
Input Admittance vs Frequency-Output Short Circuit



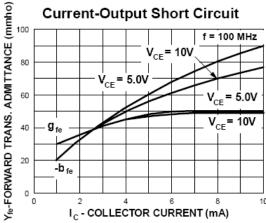
Forward Transfer Admittance vs Frequency-Output Open Circuit



Forward Trans. Admittance vs Collector

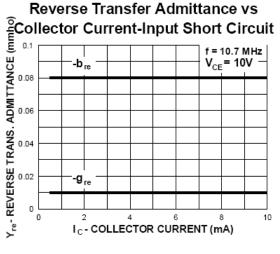


Forward Trans. Admittance vs Collector

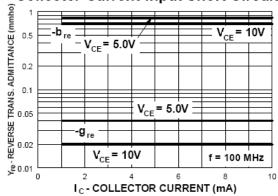


Typical Characteristics (continued)

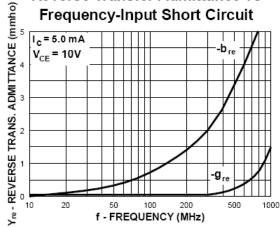




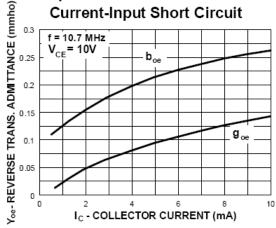
Reverse Transfer Admittance vs Collector Current-Input Short Circuit



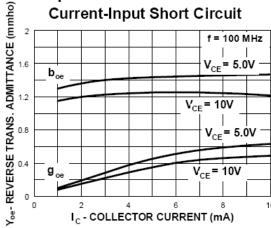
Reverse Transfer Admittance vs Frequency-Input Short Circuit



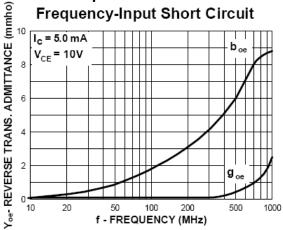
Output Admittance vs Collector Current-Input Short Circuit



Output Admittance vs Collector



Output Admittance vs Frequency-Input Short Circuit







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Rev. I31

MMBT5770 Rev. 1.0.0